L Number	Hits	Search Text	DB	Time stamp
-	83	(("screen oxide") WITH (implant or implanting)) SAME (remove or removing or removal or removed)	USPAT; US-PGPUB	2002/08/09 16:19
-	9	((("screen oxide") WITH (implant or implanting)) SAME (remove or removing or removal or removed)) SAME trench	USPAT; US-PGPUB	2002/08/09 16:15
-	149	(("sacrificial oxide") WITH (implant or implanting)) SAME (remove or removing or removal or removed)	USPAT; US-PGPUB	2002/08/09 16:22
-	9	(("sacrificial oxide") WITH (implant or implanting) with thermal) SAME (remove or removing or removal or removed)	USPAT; US-PGPUB	2002/08/09 16:24
-	11	((sacrificial) WITH (implant or implanting) with thermal) SAME (remove or removing or removal or removed)	USPAT; US-PGPUB	2002/08/09 16:27
-	11	((sacrificial) WITH (implant or implanting) with thermal) SAME (etch or etching)	USPAT; US-PGPUB	2002/08/09 16:30
-	158	((oxide) WITH (implant or implanting) with thermal) SAME (etch or etching)	USPAT; US-PGPUB	2002/08/09 16:30
-	25	(((oxide) WITH (implant or implanting) with thermal) SAME (etch or etching)) same trench	USPAT; US-PGPUB	2002/08/09 17:04
-	1	("6352936").PN.	USPAT; US-PGPUB	2002/08/09 17:07
-	1	("5989963").PN.	USPAT; US-PGPUB	2002/08/09 17:08
-	1	("5976956").PN.	USPAT; US-PGPUB	2002/08/09 17:09
-	0	(("screen oxide" with through with (thermal or thermally)) and (semiconductor or "integrated circuit")) NOT (@ad>06002001 or @rlad>06002001)	USPAT; US-PGPUB	2002/08/09 17:16
-	0	((("screen oxide" with through) SAME (thermal or thermally)) and (semiconductor or "integrated circuit")) NOT (@ad>06002001 or @rlad>06002001)	USPAT; US-PGPUB	2002/08/09 17:15
-	0	((("screen oxide" with through) and (thermal or thermally)) and (semiconductor or "integrated circuit")) NOT (@ad>06002001 or @rlad>06002001)	USPAT; US-PGPUB	2002/08/09 17:14
-	0	(("screen oxide" with (thermal or thermally)) and (semiconductor or "integrated circuit")) NOT (@ad>06002001 or @rlad>06002001)	USPAT; US-PGPUB	2002/08/09 17:14
-	0	(("screen oxide" same (thermal or thermally)) and (semiconductor or "integrated circuit")) NOT (@ad>06002001 or @rlad>06002001)	USPAT; US-PGPUB	2002/08/09 17:15
-	0	(("screen oxide" with through) and (semiconductor or "integrated circuit")) NOT (@ad>06002001 or @rlad>06002001)	USPAT; US-PGPUB	2002/08/09 17:16
-	0	(("screen oxide" with through) and (semiconductor or "integrated circuit")) NOT (@ad>06012001 or @rlad>06012001)	USPAT; US-PGPUB	2002/08/09 17:16
-	108	(("screen oxide" with through) and (semiconductor or "integrated circuit"))	USPAT; US-PGPUB	2002/08/09 17:16
-	3	(("screen oxide" with through with (thermal or thermally)) and (semiconductor or "integrated circuit"))	USPAT; US-PGPUB	2002/08/09 17:42
-	1	("6265283").PN.	USPAT; US-PGPUB	2002/08/09 17:43

L Number	Hits	Search Text	DB	Time stamp
-	102	("semi recessed" or semirecessed) WITH LOCOS	USPAT; US-PGPUB	2002/08/09 13:59
-	39	(("semi recessed" or semirecessed) WITH LOCOS) and ((groove or trench or hole or opening) same (thermal or thermally))	USPAT; US-PGPUB	2002/08/09 14:01
-	29	((("semi recessed" or semirecessed) WITH LOCOS) and ((groove or trench or hole or opening) same (thermal or thermally))) and (ion or implant)	USPAT; US-PGPUB	2002/08/09 14:04
-	23	SROX	USPAT; US-PGPUB	2002/08/09 15:05
-	20	("4135955" | "4144101" | "4244752" | "4280272" | "4282648" | "4358340" | "4385947" | "4391849" | "4411058" | "4412375" | "4419142" | "4459740" | "4468852" | "4470191" | "4473435" | "4480375" | "4481705" | "4484979" | "4509991" | "4533431").PN.	USPAT	2002/08/09 14:06
-	8	4600445.URPN.	USPAT	2002/08/09 14:06
-	11	4692992.URPN.	USPAT	2002/08/09 14:09
-	77	((sacrificial) WITH (implant$)) SAME ((remove or removing or removal or removed or etch or etching) and (trench or recess))	USPAT; US-PGPUB	2002/08/09 15:07

L Number	Hits	Search Text	DB	Time stamp
-	82	"semi recessed" WITH LOCOS	USPAT; US-PGPUB	2002/08/06 10:40
-	52	LOCOS with offset	USPAT; US-PGPUB	2002/08/06 10:54
-	3373	(source or drain) WITH (locos or "field oxide")	USPAT; US-PGPUB	2002/08/06 13:09
-	358	((source or drain) WITH (locos or "field oxide")) and offset	USPAT; US-PGPUB	2002/08/06 11:39
-	2	("4080719" | "4102733").PN.	USPAT	2002/08/06 11:02
-	241	438/298.ccls.	USPAT; US-PGPUB	2002/08/06 13:30
-	41	3755001.URPN.	USPAT	2002/08/06 11:44
-	6	("3328216" | "3655457" | "3755001" | "3764396" | "3793088" | "3796929").PN.	USPAT	2002/08/06 11:51
-	3	("3386865" | "3544858" | "3649386").PN.	USPAT	2002/08/06 13:09
-	15	5236861.URPN.	USPAT	2002/08/06 12:30
-	8	("4539744" | "5106777" | "5236861" | "5256593" | "5273928" | "5330928" | "5453395" | "5472902").PN.	USPAT	2002/08/06 12:32
-	14	("3873371" | "4013484" | "4023195" | "4027380" | "4178191" | "4253229" | "4417385" | "4466178" | "4554726" | "4698899" | "5045898" | "5100810" | "5173438" | "5240874").PN.	USPAT	2002/08/06 12:44
-	5	("4980311" | "5112772" | "5116779" | "5369051" | "5455438").PN.	USPAT	2002/08/06 12:58
-	2	("5418176" | "5422300").PN.	USPAT	2002/08/06 13:04
-	3	5946577.URPN.	USPAT	2002/08/06 13:04
-	7498	(gate) WITH (locos or "field oxide")	USPAT; US-PGPUB	2002/08/06 13:10
-	6987	((gate) WITH (locos or "field oxide")) and (MOSFET or MOS or FET or transistor)	USPAT; US-PGPUB	2002/08/06 13:11
-	124	("semi recessed" or semirecessed) SAME locos	USPAT; US-PGPUB	2002/08/06 13:11
-	5702	(((gate) WITH (locos or "field oxide")) and (MOSFET or MOS or FET or transistor)) and (ion or implant)	USPAT; US-PGPUB	2002/08/06 13:15
-	2815	(((gate) WITH (locos or "field oxide")) and (MOSFET or MOS or FET or transistor)) and ((ion or implant) SAME (thermal or oxidation or oxidizing))	USPAT; US-PGPUB	2002/08/06 13:18
-	308	((((gate) WITH (locos or "field oxide")) and (MOSFET or MOS or FET or transistor)) and ((ion or implant) SAME (thermal or oxidation or oxidizing))) and offset	USPAT; US-PGPUB	2002/08/06 13:19
-	60	438/447.ccls.	USPAT; US-PGPUB	2002/08/06 13:38
-	5	("4965221" | "5137843" | "5173444" | "5246537" | "5374584").PN.	USPAT	2002/08/06 13:32
-	168	438/525.ccls.	USPAT; US-PGPUB	2002/08/06 13:47
-	694	438/301.ccls.	USPAT; US-PGPUB	2002/08/06 13:57
-	293	438/299.ccls.	USPAT; US-PGPUB	2002/08/06 13:49
-	66	438/299.ccls. and locos	USPAT; US-PGPUB	2002/08/06 13:50
-	40	locos and offset	EPO; JPO	2002/08/06 13:50
-	629	438/301.ccls. not 438/299.ccls.	USPAT; US-PGPUB	2002/08/06 13:57
-	616	(438/301.ccls. not 438/299.ccls.) not 438/298.ccls.	USPAT; US-PGPUB	2002/08/06 13:59
-	614	((438/301.ccls. not 438/299.ccls.) not 438/298.ccls.) not 438/525.ccls.	USPAT; US-PGPUB	2002/08/06 13:58
-	105	(((438/301.ccls. not 438/299.ccls.) not 438/298.ccls.) not 438/525.ccls.) and locos	USPAT; US-PGPUB	2002/08/06 13:59
-	1548	(selective or selectively) WITH (oxide or oxidation) with (source or drain or "source/drain")	USPAT; US-PGPUB	2002/08/06 16:09

| - | 1293 | ((selective or selectively) WITH (oxide or oxidation) with (source or drain or "source/drain")) and (MOSFET or MOS or FET or transistor) | USPAT; US-PGPUB | 2002/08/06 16:09 |
| - | 396 | (((selective or selectively) WITH (oxide or oxidation) with (source or drain or "source/drain")) and (MOSFET or MOS or FET or transistor)) and (locos or recessed) | USPAT; US-PGPUB | 2002/08/06 16:10 |